

S1W0-5050xx7006-00000000-0C002

LM-80

RoHS

High-Power LED – 5050 Series

STW0LAPA

S1W0-5050xx7006-00000000-0C002 (Cool, Neutral, Warm)



Product Brief

Description

- This White Colored surface-mount LED comes in standard package dimension.
- It has a substrate made up of a molded plastic reflector sitting on top of a lead frame.
- The die is attached within the reflector cavity and the cavity is encapsulated by silicone.
- The package design coupled with careful selection of component materials allow these products to perform with high reliability



Features and Benefits

- High Intensity output and high luminance
- Size : 5.0x5.0
- Designed for high voltage operation
- SMT solderable
- RoHS compliant
- CRI line up 70

Key Applications

- General lighting
- Architectural lighting
- LED Bulbs
- Decorative / Pathway lighting

Dorf Number	Color	Nominal	Reference Code		BO
Part Number	Color	ССТ	Reference Code	Min	R9
		6500K	S1W0-5050657006-00000000-0C002	_	
	Cool White	5700K	S1W0-5050577006-00000000-0C002	_	
		5000K	S1W0-5050507006-00000000-0C002	_	
STW0LAPA- E2H1C100		4500K	S1W0-5050457006-00000000-0C002	70	No Control
		4000K	S1W0-5050407006-00000000-0C002	_	
		3500K	S1W0-5050357006-00000000-0C002	_	
14/0	Warm White	3000K	S1W0-5050307006-00000000-0C002	_	
	warm white	2700K	S1W0-5050277006-00000000-0C002	_	
		2200K	S1W0-5050227006-00000000-0C002	-	

Table 1-1. Product Selection Table



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Product Performance & Characterization Guide

Min.	Nominal	Min. Flux	Typ. Luminous	Typ. Luminous
CRI	ССТ [К] [1]	[lm]	Flux Φ _V ^[2]	Efficacy
		L	[lm]	[lm/W]
	6500	675	708.3	185.1
	5700	675	719.1	187.9
	5000	700	730.0	190.7
	4500	700	740.0	195.5
70	4000	700	740.0	195.5
	3500	650	717.8	188.4
	3000	650	703.4	184.7
	2700	625	682.3	179.1
	2200	550	620.8	163.0

Notes :

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
- (2) Seoul Semiconductor maintains a tolerance of $\pm 5\%$ on flux and power measurements.

Product Performance & Characterization Guide

Table 3. Characteristics, I_F =640mA, T_j =25°C

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Parameter	Cumhal		Unit		
Farameter	Symbol	Min.	Тур.	Max.	Unit
Forward Voltage	V _F	5.60	6.0	6.2	V
Luminous Flux	$\Phi_{v}^{[2]}$	500	-	750	lm
Correlated Color Temperature ^[3]	ССТ	2,200	-	6,500	к
CRI ^[4]	Ra	70	-	80	-
Viewing Angle	2Θ1/2	-	120	-	deg.
Thermal resistance (J to S) ^[5]	Rθ _{j-s}	-	2.0	-	K/W
ESD Sensitivity(HBM)	- Class 2 JEDEC JS-001-2017				

Table 4. Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	1000	mA
Power Dissipation	P _D	6.2	W
Junction Temperature	Tj	125	٥C
Operating Temperature	T _{opr}	-40 ~ + 100	٥C
Storage Temperature	T _{stg}	-40 ~ + 100	٥C

Notes :

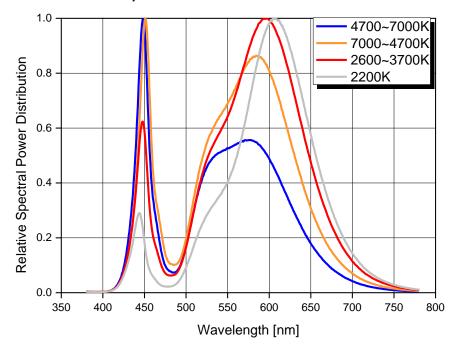
- (1) Seoul Semiconductor maintains a tolerance of $\pm 5\%$ on flux and power measurements.
- (2) Φ_V is the total luminous flux output as measured with an integrating sphere.
- (3) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
 Color coordinate : ±0.005, CCT ±5% tolerance.
- (4) Tolerance is ± 2.0 on CRI, ± 0.2 on VF measurements.
- Calculated performance values are for reference only.
- All measurements were made under the standardized environment of Seoul Semiconductor.



Characteristics Graph

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Fig 1. Color Spectrum, $T_i=25^{\circ}C$, $I_F=640mA$

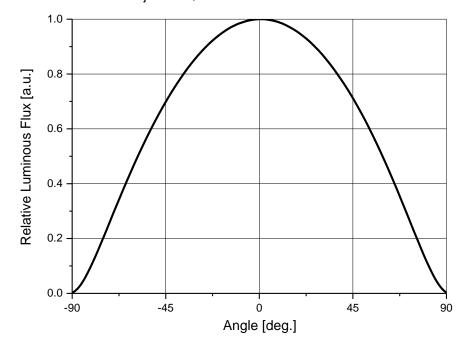




Characteristics Graph

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Fig 2. Radiant pattern, $T_j=25^{\circ}C$, $I_F=640mA$



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Characteristics Graph

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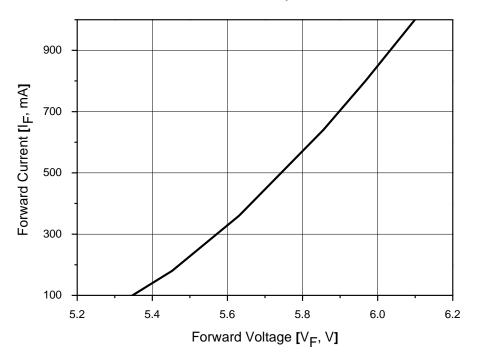
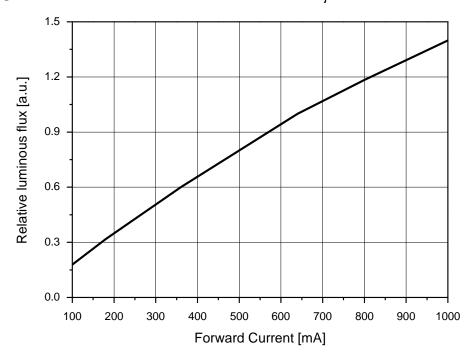


Fig 3. Forward Voltage vs. Forward Current, $\rm T_{j}=25\,^{\circ}\rm C$

Fig 4. Forward Current vs. Relative Luminous Flux, $T_i=25^{\circ}C$



• Use of less than 5mA is not recommended



Characteristics Graph

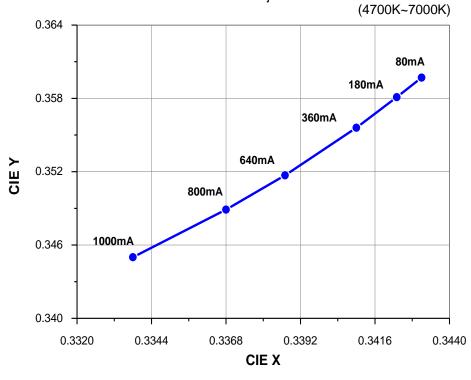
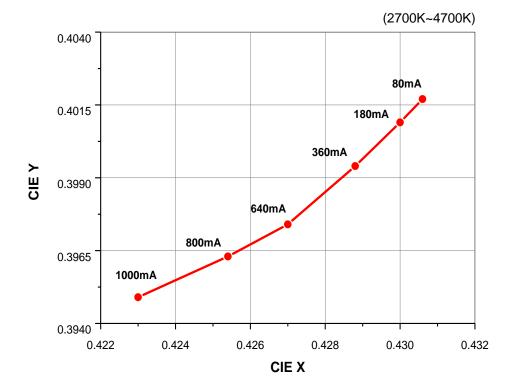


Fig 5. Forward Current vs. CIE X, Y Shift , $T_i=25^{\circ}C$





Characteristics Graph

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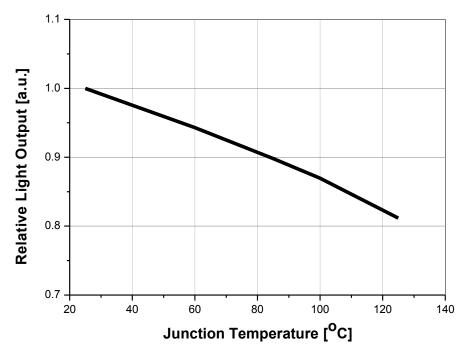
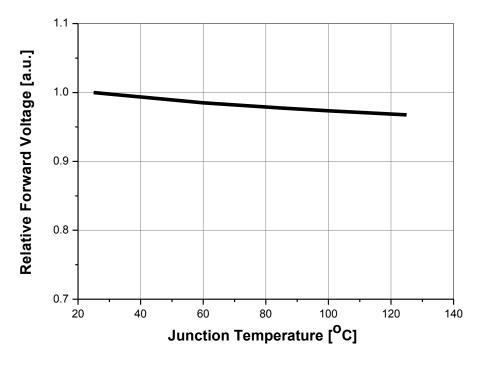


Fig 6. Relative Light Output vs. Junction Temperature, I_F =640mA

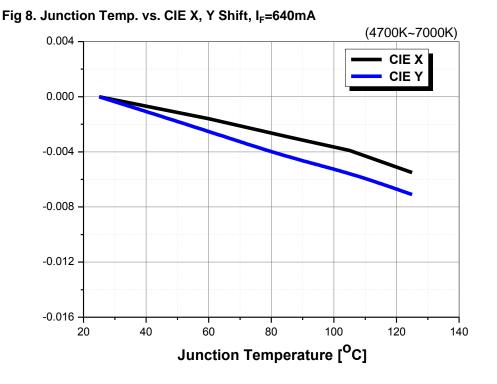
Fig 7. Relative Forward Voltage vs. Junction Temperature, I_F=640mA

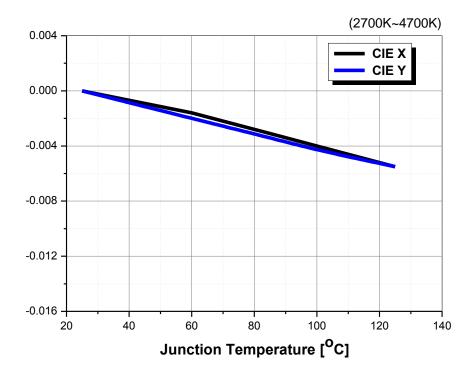




Characteristics Graph

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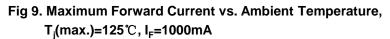


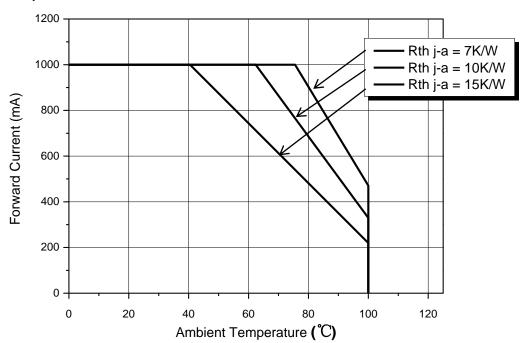


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Characteristics Graph

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Color Bin Structure

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Table 5. Bin Code description, $T_j=25^{\circ}C$, $I_F=640mA$

Part Numbe r				Color Chromati city Coordinate	Forward Voltage (V _f)			
	Bin Code	Min.	Max.		Bin Code	Min.	Max.	
	W1L	550	575	Refer to page.	Y8L	5.6	5.8	
	W1H	575	600	13 ~ 21	Y8	5.8	6.0	
	W2L	600	625		Z0	6.0	6.2	
STW0LAPA-	W2H	625	650					
E2 H1C100	W3L	650	675					
	W3H	675	700					
-	W4L	700	725					
	W4H	725	750	_				

Table 6. Luminous Flux rank distribution

CRI	сст	CIE				Flux	Rank			
	7000 ~ 6000K	А	W1L	W1H	W2L	W2H	W3L	W3H	W4L	W4H
	6000 ~ 5300K	В	W1L	W1H	W2L	W2H	W3L	W3H	W4L	W4H
	5300 ~ 4700K	С	W1L	W1H	W2L	W2H	W3L	W3H	W4L	W4H
	4700 ~ 4200K	D	W1L	W1H	W2L	W2H	W3L	W3H	W4L	W4H
70	4200 ~ 3700K	E	W1L	W1H	W2L	W2H	W3L	W3H	W4L	W4H
	3700 ~ 3200K	F	W1L	W1H	W2L	W2H	W3L	W3H	W4L	W4H
	3200 ~ 2900K	G	W1L	W1H	W2L	W2H	W3L	W3H	W4L	W4H
	2900 ~ 2600K	Н	W1L	W1H	W2L	W2H	W3L	W3H	W4L	W4H
	2600 ~ 2200K	К	W1L	W1H	W2L	W2H	W3L	W3H	W4L	W4H



Available ranks Not yet available ranks

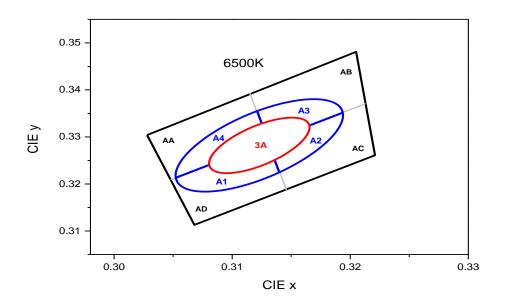
• All measurements were made under the standardized environment of Seoul Semiconductor.

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CIE Chromaticity Diagram (Cool white), $T_i=25^{\circ}C$, $I_F=640mA$



3step(3A)	5step		
Center point	0.3123 : 0.3282	Center point	0.3123 : 0.3282	
Major Axis a	0.0067	Major Axis a	0.0112	
Minor Axis b	0.0029	Minor Axis b	0.0048	
Ellipse Rotation Angle	59	Ellipse Rotation Angle	59	

A	1	A	2	A	3	A	.4
CIE X	CIE Y						
0.3052	0.3213	0.314	0.3224	0.3194	0.3352	0.3121	0.3356
0.3081	0.3241	0.3136	0.3251	0.3165	0.3324	0.3125	0.3329
0.314	0.3224	0.3194	0.3352	0.3121	0.3356	0.3052	0.3213
0.3136	0.3251	0.3165	0.3324	0.3125	0.3329	0.3081	0.3241

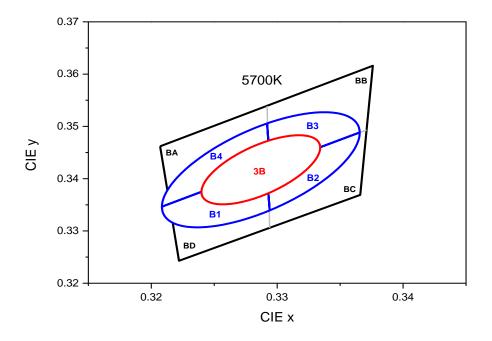
A	A	A	В	A	c	A	D
CIE X	CIE Y						
0.3028	0.3304	0.3115	0.3393	0.3131	0.329	0.3048	0.3209
0.3048	0.3209	0.3131	0.329	0.3146	0.3187	0.3068	0.3113
0.3131	0.329	0.3213	0.3371	0.3221	0.3261	0.3146	0.3187
0.3115	0.3393	0.3205	0.3481	0.3213	0.3371	0.3131	0.329

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CIE Chromaticity Diagram (Cool white), $\, T_{j} {=} 25\, {}^{\circ} {\rm C} \, , \, I_{F} {=} 640 mA$



3step(3	3B)	5step		
Center point	0.3287 : 0.3417	Center point	0.3287 : 0.3417	
Major Axis a	0.0075	Major Axis a	0.0124	
Minor Axis b	0.0032	Minor Axis b	0.0053	
Ellipse Rotation Angle	59	Ellipse Rotation Angle	59	

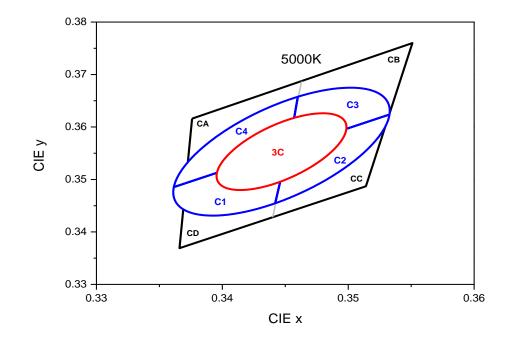
В	1	В	2	В	3	В	4
CIE X	CIE Y						
0.3209	0.3347	0.3294	0.3339	0.3365	0.3488	0.3292	0.3505
0.324	0.3375	0.3293	0.3373	0.3334	0.346	0.3293	0.3472
0.3294	0.3339	0.3365	0.3488	0.3292	0.3505	0.3209	0.3347
0.3293	0.3373	0.3334	0.346	0.3293	0.3472	0.324	0.3375

В	A	В	В	В	с	В	D
CIE X	CIE Y						
0.3207	0.3462	0.3292	0.3539	0.3293	0.3423	0.3215	0.3353
0.3215	0.3353	0.3293	0.3423	0.3294	0.3306	0.3222	0.3243
0.3293	0.3423	0.3371	0.3493	0.3366	0.3369	0.3294	0.3306
0.3292	0.3539	0.3376	0.3616	0.3371	0.3493	0.3293	0.3423

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CIE Chromaticity Diagram (Cool white), $\, T_{j} {=} 25\, {}^{\circ} {\rm C} \, , \, I_{F} {=} 640 mA$

3step(:	3C)	5step		
Center point	0.3447 : 0.3553	Center point	0.3447 : 0.3553	
Major Axis a	0.0082	Major Axis a	0.0137	
Minor Axis b	0.0035	Minor Axis b	0.0059	
Ellipse Rotation Angle	60	Ellipse Rotation Angle	60	

C	1	С	2	С	3	C	4
CIE X	CIE Y						
0.3361	0.3485	0.3442	0.3455	0.3533	0.3624	0.346	0.3658
0.3396	0.3513	0.3446	0.3496	0.3498	0.3596	0.3457	0.3617
0.3442	0.3455	0.3533	0.3624	0.346	0.3658	0.3361	0.3485
0.3446	0.3496	0.3498	0.3596	0.3457	0.3617	0.3396	0.3513

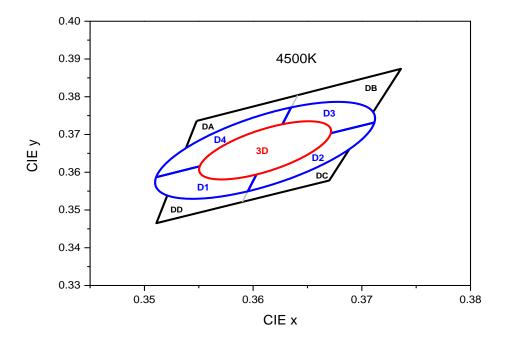
С	A	с	В	с	с	С	D
CIE X	CIE Y						
0.3376	0.3616	0.3463	0.3687	0.3452	0.3558	0.3371	0.3493
0.3371	0.3493	0.3452	0.3558	0.344	0.3428	0.3366	0.3369
0.3452	0.3558	0.3533	0.3624	0.3514	0.3487	0.344	0.3428
0.3463	0.3687	0.3551	0.376	0.3533	0.3624	0.3452	0.3558

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CIE Chromaticity Diagram (Neutral white), $\, T_{j} {=} 25\, {}^{\circ} \!\! \mathbb{C}, \, I_{F} {=} 640 mA$



3step(:	3D)	5step		
Center point	0.3611 : 0.3658	Center point	0.3611 : 0.3658	
Major Axis a	0.009	Major Axis a	0.015	
Minor Axis b	0.0039	Minor Axis b	0.0065	
Ellipse Rotation Angle	55	Ellipse Rotation Angle	55	

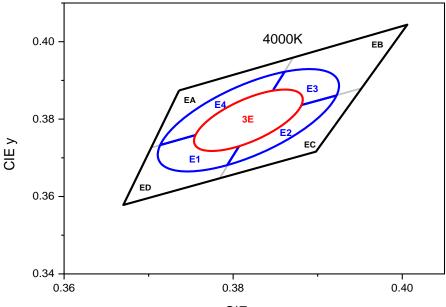
D	1	D	2	D	3	D	4
CIE X	CIE Y						
0.3511	0.3587	0.3595	0.3549	0.3712	0.3732	0.3635	0.3772
0.3551	0.3616	0.3603	0.3594	0.3671	0.3703	0.3627	0.3727
0.3595	0.3549	0.3712	0.3732	0.3635	0.3772	0.3511	0.3587
0.3603	0.3594	0.3671	0.3703	0.3627	0.3727	0.3551	0.3616

D	A	D	В	D	с	D	D
CIE X	CIE Y						
0.3548	0.3736	0.3641	0.3804	0.3616	0.3663	0.3530	0.3601
0.3530	0.3601	0.3616	0.3663	0.3590	0.3521	0.3511	0.3465
0.3616	0.3663	0.3703	0.3726	0.3670	0.3578	0.3590	0.3521
0.3641	0.3804	0.3736	0.3874	0.3703	0.3726	0.3616	0.3663

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CIE x

3step(BE)	5step		
Center point	0.3818 : 0.3797	Center point	0.3818 : 0.3797	
Major Axis a	0.0094	Major Axis a	0.0157	
Minor Axis b	0.0040	Minor Axis b	0.0067	
Ellipse Rotation Angle	54	Ellipse Rotation Angle	54	

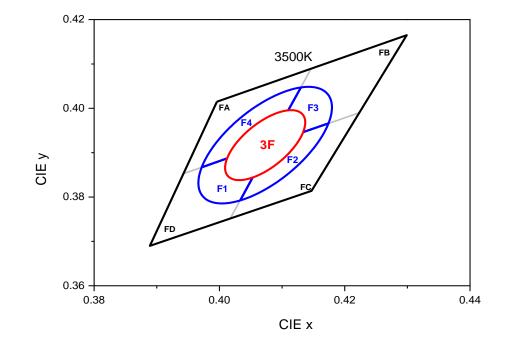
E	1	E	2	E	3	E	4
CIE X	CIE Y						
0.3714	0.3733	0.3793	0.3681	0.3922	0.3861	0.3861	0.3923
0.3756	0.3759	0.3807	0.373	0.388	0.3836	0.3847	0.3874
0.3793	0.3681	0.3922	0.3861	0.3861	0.3923	0.3714	0.3733
0.3807	0.373	0.388	0.3836	0.3847	0.3874	0.3756	0.3759

E	A	E	В	E	с	E	D
CIE X	CIE Y						
0.3736	0.3874	0.3871	0.3959	0.3828	0.3803	0.3703	0.3726
0.3703	0.3726	0.3828	0.3803	0.3784	0.3647	0.367	0.3578
0.3828	0.3803	0.3952	0.388	0.3898	0.3716	0.3784	0.3647
0.3871	0.3959	0.4006	0.4044	0.3952	0.388	0.3828	0.3803

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3step(:	3F)	5step		
Center point	0.4073 : 0.3917	Center point	0.4073 : 0.3917	
Major Axis a	0.0093	Major Axis a	0.0155	
Minor Axis b	0.0041	Minor Axis b	0.0069	
Ellipse Rotation Angle	54	Ellipse Rotation Angle	54	

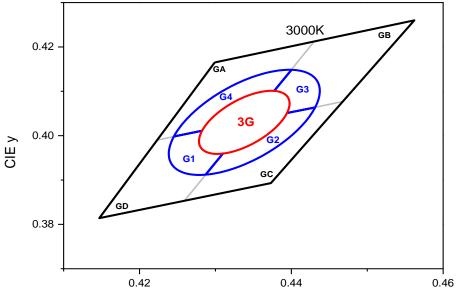
F	1	F	2	F	3	F	4
CIE X	CIE Y						
0.3972	0.3867	0.4033	0.3792	0.4174	0.3966	0.413	0.4047
0.4012	0.3887	0.4053	0.3844	0.4133	0.3946	0.411	0.3996
0.4033	0.3792	0.4174	0.3966	0.413	0.4047	0.3972	0.3867
0.4053	0.3844	0.4133	0.3946	0.411	0.3996	0.4012	0.3887

F.	A	F	В	F	c	F	D
CIE X	CIE Y						
0.3996	0.4015	0.4146	0.4089	0.4082	0.392	0.3943	0.3853
0.3943	0.3853	0.4082	0.392	0.4017	0.3751	0.3889	0.369
0.4082	0.392	0.4223	0.399	0.4147	0.3814	0.4017	0.3751
0.4146	0.4089	0.4299	0.4165	0.4223	0.399	0.4082	0.392

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3step(3	G)	5step		
Center point	0.4338 : 0.4030	Center point	0.4338 : 0.4030	
Major Axis a	0.0083	Major Axis a	0.0139	
Minor Axis b	0.0041	Minor Axis b	0.0068	
Ellipse Rotation Angle	53	Ellipse Rotation Angle	53	

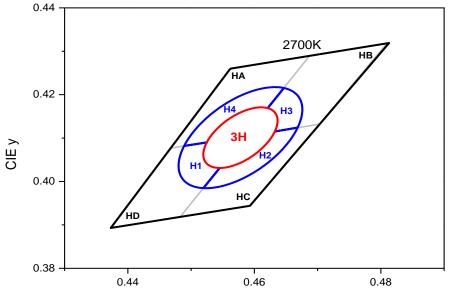
G	1	G	2	G	3	G	4
CIE X	CIE Y						
0.4245	0.3998	0.4287	0.3912	0.4432	0.4064	0.44	0.4148
0.4282	0.4011	0.431	0.396	0.4394	0.4051	0.4377	0.41
0.4287	0.3912	0.4432	0.4064	0.44	0.4148	0.4245	0.3998
0.431	0.396	0.4394	0.4051	0.4377	0.41	0.4282	0.4011

G	Α	G	В	G	с	G	D
CIE X	CIE Y						
0.4299	0.4165	0.443	0.4212	0.4345	0.4033	0.4223	0.399
0.4223	0.399	0.4345	0.4033	0.4259	0.3853	0.4147	0.3814
0.4345	0.4033	0.4468	0.4077	0.4373	0.3893	0.4259	0.3853
0.443	0.4212	0.4562	0.426	0.4468	0.4077	0.4345	0.4033

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Color Bin Structure

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CIE x

3step(:	3H)	5step		
Center point	0.4578 : 0.4101	Center point	0.4578 : 0.4101	
Major Axis a	0.0081	Major Axis a	0.0135	
Minor Axis b	0.0042	Minor Axis b	0.007	
Ellipse Rotation Angle	54	Ellipse Rotation Angle	54	

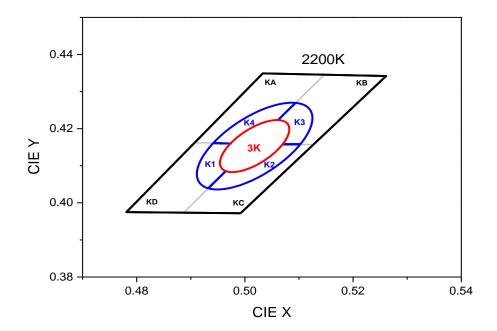
н	1	н	2	н	3	н	4
CIE X	CIE Y						
0.4489	0.4082	0.4519	0.3984	0.4668	0.4124	0.4647	0.4216
0.4525	0.409	0.4545	0.4031	0.4632	0.4115	0.4621	0.4169
0.4519	0.3984	0.4668	0.4124	0.4647	0.4216	0.4489	0.4082
0.4545	0.4031	0.4632	0.4115	0.4621	0.4169	0.4525	0.409

н	A	н	В	н	c	н	D
CIE X	CIE Y						
0.4562	0.426	0.4687	0.4289	0.4585	0.4104	0.4468	0.4077
0.4468	0.4077	0.4585	0.4104	0.4483	0.3919	0.4373	0.3893
0.4585	0.4104	0.4703	0.4132	0.4593	0.3944	0.4483	0.3919
0.4687	0.4289	0.481	0.4319	0.4703	0.4132	0.4585	0.4104

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Color Bin Structure

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3step(:	3К)	5step		
Center point	0.5018 : 0.4153	Center point	0.5018 : 0.4153	
Major Axis a	0.0086	Major Axis a	0.0144	
Minor Axis b	0.004	Minor Axis b	0.0066	
Ellipse Rotation Angle	49	Ellipse Rotation Angle	49	

к	1	к	2	к	3	к	4
CIE X	CIE Y						
0.4942	0.4161	0.4932	0.4039	0.5102	0.4158	0.5094	0.427
0.4974	0.416	0.4965	0.4086	0.507	0.4158	0.5061	0.4223
0.4932	0.4039	0.5102	0.4158	0.5094	0.427	0.4942	0.4161
0.4965	0.4086	0.507	0.4158	0.5061	0.4223	0.4974	0.416

к	A	к	В	к	с	к	D
CIE X	CIE Y						
0.5033	0.4349	0.5147	0.4346	0.5017	0.416	0.4907	0.4162
0.4907	0.4162	0.5017	0.416	0.4887	0.3974	0.4781	0.3975
0.5017	0.416	0.5127	0.4157	0.4992	0.3972	0.4887	0.3974
0.5147	0.4346	0.5261	0.4342	0.5127	0.4157	0.5017	0.416



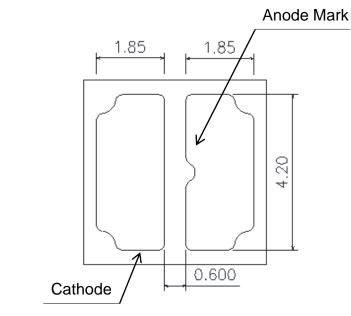
5.00

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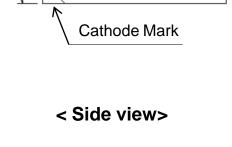
< Bottom View >

Mechanical Dimensions





5.00





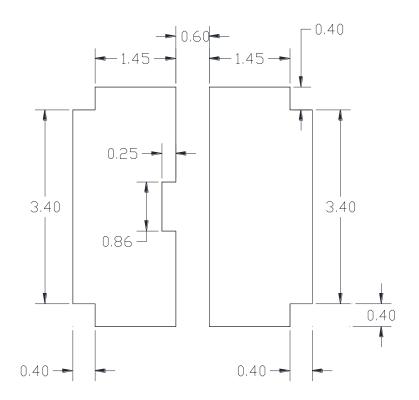
Notes :

- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) Undefined tolerance is ± 0.2 mm



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Recommended Solder Pad



Notes :

- (1) All dimensions are in millimeters.
- (2) Scale: none
- (3) Undefined tolerance is $\pm 0.2 \text{mm}$
- (4) This drawing without tolerances are for reference only.

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Reflow Soldering Characteristics

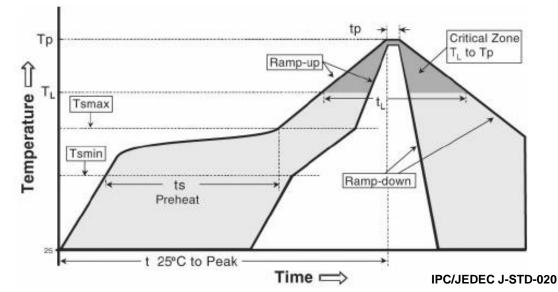


Table 7.

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Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate $(T_{smax} \text{ to } T_p)$	3° C/second max.	3° C/second max.
Preheat - Temperature Min (T _{smin}) - Temperature Max (T _{smax}) - Time (T _{smin} to T _{smax}) (t _s)	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-180 seconds
Time maintained above: - Temperature (T _L) - Time (t _L)	183 ℃ 60-150 seconds	217 °C 60-150 seconds
Peak Temperature (T _p)	215 ℃	260 ℃
Time within 5°C of actual Peak Temperature (t _p)2	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

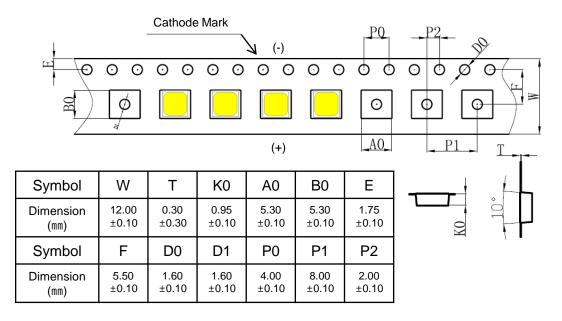
Caution

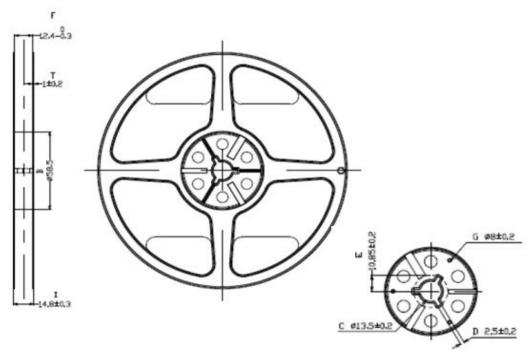
- (1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
- (2) Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
- (3) Die slug is to be soldered.
- (4) When soldering, do not put stress on the LEDs during heating.
- (5) After soldering, do not warp the circuit board.



Emitter Tape & Reel Packaging

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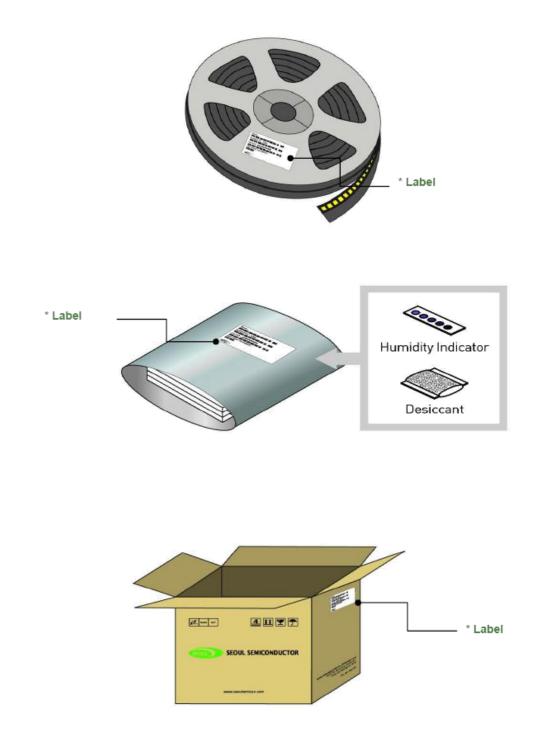
Notes :

- (1) Quantity : 7 inch reel type (2,000 pcs / Reel \pm 1pcs)
- (2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be $\pm 0.2 \text{mm}$
- (3) Adhesion Strength of Cover Tape : Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of 10° to the carrier tape
- (4) Package : P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package.



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Emitter Tape & Reel Packaging





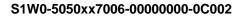
Product Nomenclature

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Table 8. Part Numbering System

Part Number Code	Description	Part Number	Value
X ₁	Company	S	Seoul Semiconductor
X ₂	Level of Integration	1	Discrete LED
X ₃ X ₄	Technology	WO	General White
X ₅		-	
X ₆ X ₇ X ₈ X ₉	Dimension	5050	5.0x5.0mm
X ₁₀ X ₁₁	ССТ	ХХ	65:6500K 57:5700K 50:5000K 40:4000K 35:3500K 30:3000K 27:2700K
X ₁₂ X ₁₃	CRI	70	CRI70
X ₁₄ X ₁₅	Vf	06	
X ₁₆		-	
X ₁₇ X ₁₈ X ₁₉	Characteristic code Flux Rank	000	
X ₂₀ X ₂₁ X ₂₂	Characteristic code Vf Rank	000	
X ₂₃ X ₂₄	Characteristic code Color Step	хх	3S:3step ellipse 5S:5step ellipse
X ₂₅		-	
X ₂₆ X ₂₇	Туре	0C	
X ₂₈ X ₂₉ X ₃₀	Internal code	002	

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Handling of Silicone Resin for LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.





(2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.

(3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.

(4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

(5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin. Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.

(6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this. product with acid or sulfur material in sealed space.

Precaution for Use

(1) Storage

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To avoid the moisture penetration, we recommend store in a dry box with a desiccant . The recommended storage temperature range is 5° to 30° and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use SMT techniques properly when you solder the LED as separation of the lens may affect the light output efficiency.

Pay attention to the following:

- a. Recommend conditions after opening the package
 - Sealing / Temperature : 5 ~ 40 $^\circ\!\mathrm{C}$ Humidity : less than RH30%
- b. If the package has been opened more than 4 week(MSL_2a) or the color of the

desiccant changes, components should be dried for 10-12hr at $60{\pm}5\,^\circ\!\!\mathbb{C}$

(3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.

(4) Do not rapidly cool device after soldering.

(5) Components should not be mounted on warped (non coplanar) portion of PCB.

(6) Radioactive exposure is not considered for the products listed here in.

(7) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.

(8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.

(9) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.

(10) Don't recommend to use it for cold storage lighting.

(11) LEDs must be stored properly to maintain the device. If the LEDs are stored for 3 months or more after being shipped from Seoul Semiconductor. A sealed container with a nitrogen atmosphere should be used for storage.

(12) The appearance and specifications of the product may be modified for improvement without notice.



Precaution for Use

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(13) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.

(14) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.

(15) The slug is electrically isolated.

(16) Attaching LEDs, do not use adhesives that outgas organic vapor.

(17) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.

(18) LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.

a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)



Precaution for Use

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package

(If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)

- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package
- (shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.

c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:

- A surge protection circuit
- An appropriately rated over voltage protection device
- A current limiting device



Company Information

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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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